

View Online at <https://aerobasegroup.com/nsn/5961-01-111-5863>

**Inclosure Material:**

Metal all transistor

**Overall Length:**

1.563 inches all transistor

**Overall Height:**

0.350 inches all transistor

**Overall Width:**

1.050 inches all transistor

**Mounting Facility Quantity:**

2 all transistor

**Internal Configuration:**

Junction contact all transistor

**Joint Electronic Device Engineering Council/jedec/case Outline Designation:**

To-2o4aa all transistor

**Internal Junction Configuration:**

Npn all transistor

**Component Function Relationship:**

Matched

**Component Name And Quantity:**

2 transistor

**Mounting Method:**

Unthreaded hole all transistor

**Semiconductor Material:**

Silicon all transistor

**Voltage Rating In Volts Per Characteristic:**

350.0 breakdown voltage, collector-to-emitter, base open all transistor

**Current Rating Per Characteristic:**

8.00 amperes source cutoff current all transistor

**Power Rating Per Characteristic:**

125.0 watts small-signal input power, common-collector absolute all transistor

**Transfer Ratio:**

12.0 static forward current transfer ratio, common-emitter all transistor and 60.0 static forward current transfer ratio, common-emitter all transistor

**Maximum Operating Temperature Per Measurement Point:**

175.0 degrees celsius junction all transistor

**Terminal Type And Quantity:**

2 pin all transistor and 1 case all transistor

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

No

**Fiig:**

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